

Technical Data Data Sheet N1797, Rev. A Green Products

ST1045S-A

ST1045S-A SCHOTTKY RECTIFIER

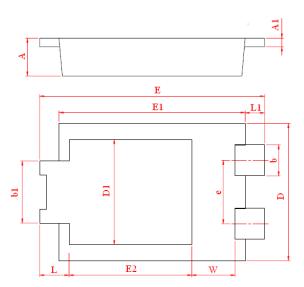
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 150 °C TJ operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request
- This is an AEC-Q101 qualified device

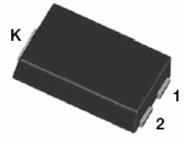
Mechanical Dimensions: In mm/Inches

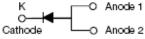


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ТО-277В			
Min.	Max.	Min.	Max.
0.95	1.25	0.037	0.049
0.20	0.30	0.008	0.012
0.85	0.95	0.033	0.037
1.70	1.90	0.067	0.075
3.88	4.08	0.153	0.161
2.90	3.20	0.114	0.126
1.74	1.94	0.069	0.076
6.30	6.70	0.248	0.264
5.28	5.48	0.208	0.216
3.40	3.70	0.134	0.146
0.70	1.00	0.028	0.039
0.41	0.71	0.016	0.028
1.10	1.40	0.043	0.055
In mm		In inch	
	0.95 0.20 0.85 1.70 3.88 2.90 1.74 6.30 5.28 3.40 0.70 0.41 1.10	Min. Max. 0.95 1.25 0.20 0.30 0.85 0.95 1.70 1.90 3.88 4.08 2.90 3.20 1.74 1.94 6.30 6.70 5.28 5.48 3.40 3.70 0.70 1.00 0.41 0.71 1.10 1.40	Min. Max. Min. 0.95 1.25 0.037 0.20 0.30 0.008 0.85 0.95 0.033 1.70 1.90 0.067 3.88 4.08 0.153 2.90 3.20 0.114 1.74 1.94 0.069 6.30 6.70 0.248 5.28 5.48 0.208 3.40 3.70 0.134 0.70 1.00 0.028 0.41 0.71 0.016 1.10 1.40 0.043

TO-277B(JK)

China - Germany - Korea - Singapore - United States http://www.smc-diodes.com - sales@ smc-diodes.com -





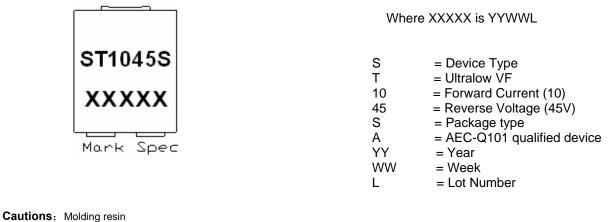


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Marking Diagram:



Epoxy resin UL: 94V-0

Ordering Information:

Device	Package	Shipping
ST1045S-A	TO-277B	5000pcs/ reel
	(Pb-Free)	5000pc3/ Teel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	45	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C = 80 °C rectangular wave form	10	A
Peak One Cycle Non-Repetitive Surge Current(per leg)	I _{FSM}	8.3 ms, half Sine pulse	150	А



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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (per leg)*	V _{F1}	@ 5A, Pulse, T _J = 25 °C @ 10A, Pulse, T _J = 25 °C	0.43 0.49	0.51 0.57	V
	V _{F2}	@ 5A, Pulse, $T_J = 125 \text{ °C}$ @ 10A, Pulse, $T_J = 125 \text{ °C}$	0.32 0.41	0.43 0.50	V
Reverse Current (per leg) *	I _{R1}	$@V_R = rated V_R$ T _J = 25 °C	0.017	0.80	mA
	I _{R2}	@V _R = rated V _R T _J = 125 °C	15	100	mA
Junction Capacitance (per leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	656	-	pF

* Pulse Width < 300µs, Duty Cycle <2%

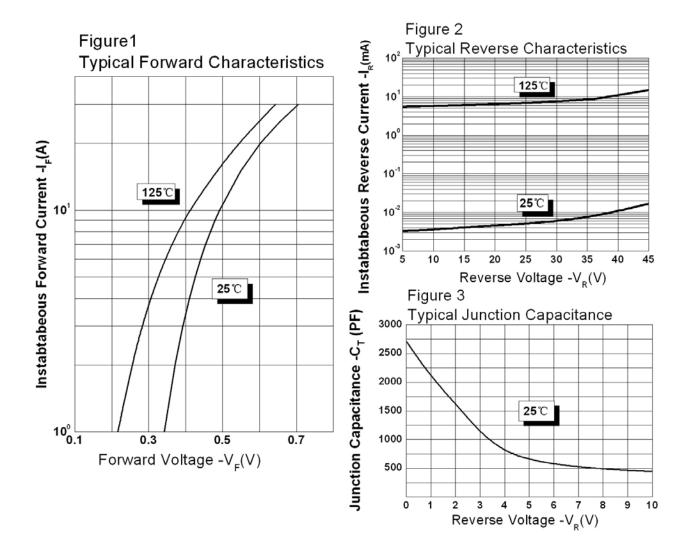
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	$R_{ ext{ heta}JA}$	DC operation	75	°C/W
Approximate Weight	wt	-	0.08	g
Case Style		TO-227B		



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